#### 1A SURFACE MOUNT GLASS PASSIVATED BRIDGE RECTIFIER

#### **FEATURES:**

Glass Passivated Chip Junction

Reverse Voltage - 100 to 1000 V

Forward Current - 1 A

High Surge Current Capability

**Designed for Surface Mount Application** 

#### **MECHANICAL DATA**

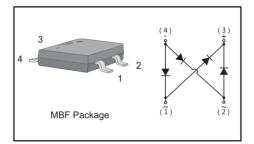
· Case: MBF

• Terminals: Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 75mg 0.0026oz

### **PINNING**

PIN	DESCRIPTION
1	Input Pin ( ~ )
2	Input Pin ( ~ )
3	Output Anode ( + )
4	Output Cathode ( - )



### Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Parameter	Symbols	MB1F-10	MB2F-10	MB4F-10	MB6F-10	MB8F-10	MB10F-10	Units
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	100	200	400	600	800	1000	V
Maximum RMS voltage	$V_{RMS}$	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V <sub>DC</sub>	100	200	400	600	800	1000	V
Average Rectified Output Current @ Fig.1	Io	1.0						А
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)	I <sub>FSM</sub>	35						А
Peak Forward Surge Current 1.0 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)	I <sub>FSM</sub>	70					А	
I²t Rating for fusing(3ms≤t≤8.3ms)	l <sup>2</sup> t	5.1						A <sup>2</sup> S
Maximum Forward Voltage at 1.0 A	V <sub>F</sub>	1.1					V	
Maximum DC Reverse Current at Rated DC Blocking Voltage $@T_A = 25  ^{\circ}\text{C}$ $@T_A = 125  ^{\circ}\text{C}$	I <sub>R</sub>	5 100					μΑ	
Typical Junction Capacitance ( Note1 )	C <sub>j</sub>	7					pF	
Typical Thermal Resistance ( Note2 )	$\begin{array}{c} R_{\theta JA} \\ R_{\theta JC} \\ R_{\theta JL} \end{array}$	45 15 25					°C/W	
Operating and Storage Temperature Range	$T_j$ , $T_{stg}$	-55 ~ <b>+</b> 150					°C	

Note: 1. Measured at 1MHz and applied reverse voltage of 4 V D.C.

2. Mounted on glass epoxy PC board 4X1.5" X 1.5" (3.81 X 3.81 cm) copper pad.

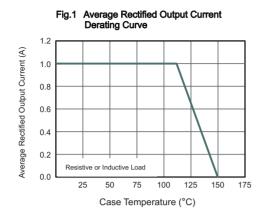


Fig.3 Typical Forward Characteristic

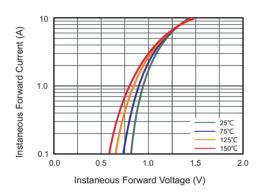


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

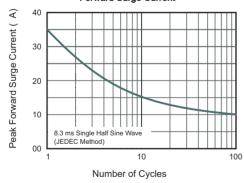


Fig.2 Typical Instaneous Reverse Characteristics

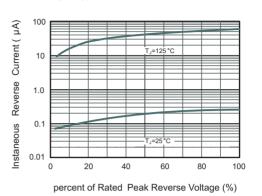
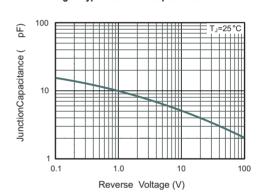


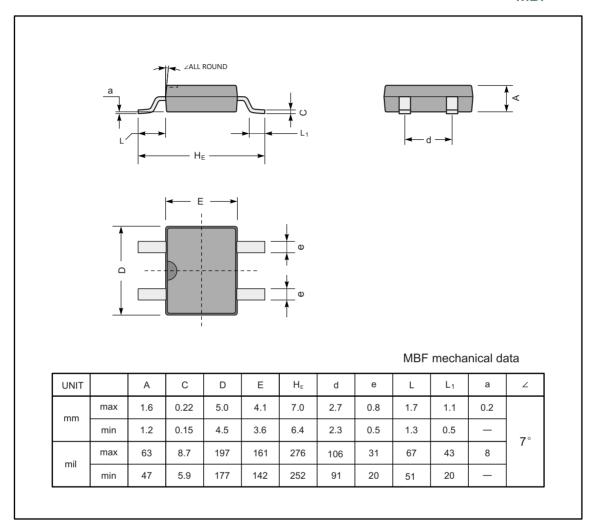
Fig.4 Typical Junction Capacitance



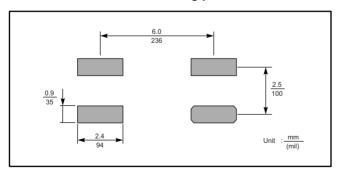
## PACKAGE OUTLINE

Plastic surface mounted package; 4 leads

### **MBF**



# The recommended mounting pad size



## Marking

Type number	Marking code				
MB1F-10	10M1				
MB2F-10	10M2				
MB4F-10	10M4				
MB6F-10	10M6				
MB8F-10	10M8				
MB10F-10	10M10				

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